

Bipolar Transistors Silicon PNP Epitaxial Type (PCT Process)(Bias Resistor built-in Transistor)

# RN2114/15/16/17/18

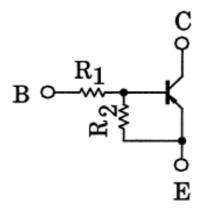
### 1. Applications

- Switching
- · Inverter Circuits
- · Interfacing
- · Driver Circuits

#### 2. Features

- (1) AEC-Q101 qualified (Please see the orderable part number list)
- (2) The integrated bias resistor reduces the number of external parts required, making it possible to reduce system size and assembly time.
- (3) Toshiba offers transistors with a wide range of resistance to accommodate various circuit designs.
- (4) Complementary to RN1114 to RN1118

### 3. Equivalent Circuit



#### 4. Bias Resistor Values

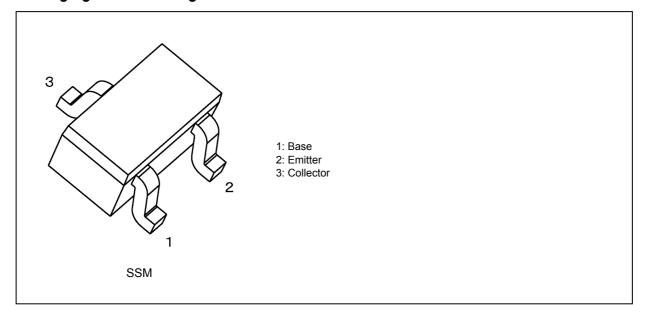
Part No.	R1 (kΩ)	R2 (kΩ)
RN2114	1	10
RN2115	2.2	10
RN2116	4.7	10
RN2117	10	4.7
RN2118	47	10

Start of commercial production

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## 5. Packaging and Pin Assignment



# 6. Orderable part number

Orderable part number		AEC-Q101	Note	Note	
RN2114	RN2114,LF	_		General Use	
	RN2114,LXGF	YES	(Note 1)	Unintended Use (Note 1)	
RN2115	RN2115,LF	_		General Use	
	RN2115,LXGF	YES	(Note 1)	Unintended Use (Note 1)	
	RN2115,LXHF	YES		Automotive Use	
RN2116	RN2116,LF	_		General Use	
	RN2116,LXGF	YES	(Note 1)	Unintended Use (Note 1)	
	RN2116,LXHF	YES		Automotive Use	
RN2117	RN2117(TE85L,F)	_		General Use	
	_	YES	(Note 1)	Unintended Use (Note 1)	

Note 1: For more information, please contact our sales or use the inquiry form on our website.



# 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

Characterist	Symbol	Rating	Unit	
Collector-base voltage	RN2114~RN2118	V <sub>CBO</sub>	-50	V
Collector-emitter voltage		V <sub>CEO</sub>	-50	
Emitter-base voltage	RN2114	V <sub>EBO</sub>	-5	V
	RN2115	]	-6	
	RN2116	]	-7	
	RN2117	1	-15	
	RN2118	1	-25	
Collector current	RN2114~RN2118	Ic	-100	mA
Collector power dissipation		P <sub>C</sub>	100	mW
Junction temperature		Tj	150	°C
Storage temperature		T <sub>stg</sub>	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



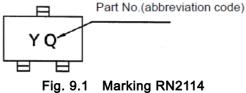
# 8. Electrical Characteristics (Unless otherwise specified, $T_a$ = 25 °C)

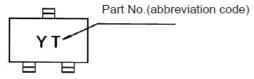
Collector cut-off current   RN21144   RN2116   Ican   VcB = -50 V, Ig = 0 mA	Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Emilter cut-off current   RN2114   EBO   Veg = -30 V, Ig = 0 mA   -3.5   -3.00   -3			I <sub>CBO</sub>	$V_{CB} = -50 \text{ V}, I_{E} = 0 \text{ mA}$		_	-100	nA
$ \begin{array}{ c c c c c } \hline RN2115 \\ RN2116 \\ RN2117 \\ \hline RN2117 \\ \hline RN2117 \\ \hline RN2118 \\ \hline RN2117 \\ \hline RN2118 \\ \hline RN2118 \\ \hline RN2118 \\ \hline RN2118 \\ \hline RN2117 \\ \hline Collector-emitter saturation voltage (ON) \\ \hline RN2114 \\ RN2115 \\ \hline RN2116 \\ \hline RN2116 \\ \hline RN2116 \\ \hline RN2117 \\ \hline RN2118 \\ \hline RN2116 \\ \hline RN2116 \\ \hline RN2117 \\ \hline RN2118 \\ \hline RN2118 \\ \hline RN2118 \\ \hline RN2116 \\ \hline RN2117 \\ \hline RN2118 \\ \hline RN2116 \\ \hline RN2117 \\ \hline RN2118 \\ \hline RN2118 \\ \hline RN2116 \\ \hline RN2117 \\ \hline RN2118 \\ \hline RN2118 \\ \hline RN2116 \\ \hline RN2117 \\ \hline RN2118 \\ \hline RN2118 \\ \hline RN2116 \\ \hline RN2117 \\ \hline RN2118 \\ \hline RN2118$		RN2118	I <sub>CEO</sub>	$V_{CE} = -50 \text{ V}, I_{B} = 0 \text{ mA}$	_	_	-500	
RN2116   RN2117   RN2118   RN2118   RN2114   RN2117   RN2118   RN2118   RN2114   RN2116   RN2118   RN2118   RN2114   RN2116	Emitter cut-off current	RN2114	I <sub>EBO</sub>	V <sub>EB</sub> = -5 V, I <sub>C</sub> = 0 mA	-0.35	_	-0.65	mA
RN2117   RN2118   V <sub>EB</sub> = -15 V, I <sub>C</sub> = 0 mA   -0.78   -0.146   -0.63   -0.		RN2115		$V_{EB} = -6 \text{ V}, I_{C} = 0 \text{ mA}$	-0.37	_	-0.71	
RN2118   RN2114   RN2116		RN2116		V <sub>EB</sub> = -7 V, I <sub>C</sub> = 0 mA	-0.36	_	-0.68	
DC current gain   RN2114 - RN2116   RN2117   RN2118   RN2117   RN2118   RN2114 ~ RN2118   RN2118   RN2118   RN2118   RN2118   RN2118   RN2118   RN2115   RN2116   RN2118   RN2116   RN2116   RN2116   RN2116   RN2116   RN2118   RN2116   RN2116   RN2116   RN2116   RN2116   RN2118   RN2118   RN2118   RN2116   RN2116   RN2116   RN2116   RN2116   RN2118   RN2116   RN2116   RN2116   RN2116   RN2118   RN2118   RN2118   RN2116   RN2118   RN2116   RN2117   RN2118   RN2116		RN2117		V <sub>EB</sub> = -15 V, I <sub>C</sub> = 0 mA	-0.78	_	-1.46	
RN2118   RN2117   RN2114   RN2114   RN2115   RN2115   RN2116   RN2117   RN2118   RN2116   RN2116   RN2117   RN2118   RN2116   RN2116   RN2117   RN2118   RN2116   RN2117   RN2116   RN2116   RN2117   RN2116   RN2116   RN2117   RN216   RN2116   RN2117   RN216   RN2116   RN2117   RN216   RN2116   RN2117   RN216		RN2118		V <sub>EB</sub> = -25 V, I <sub>C</sub> = 0 mA	-0.33	_	-0.63	
Collector-emitter saturation voltage (ON)   RN2114 \( \text{RN2118} \) RN2114 \( \text{RN2118} \) RN2114 \( \text{RN2118} \) RN2115   RN2116   RN2117   RN2118   RN2117   RN2118   RN2116   RN2117   RN2118   RN2116   RN2117   RN2118   RN2116   RN2117   RN2118   RN2116   RN2118   RN2117   RN2118   RN2116   RN2116   RN2116   RN2116   RN2118   RN2116   R	DC current gain	1 '1	h <sub>FE</sub>	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$	50	_	_	_
voltage         RN2118         V(ON)         V <sub>C</sub> = -0.2 V, I <sub>C</sub> = -5 mA         -0.5		RN2117			30	_	_	_
RN2115   RN2116   RN2117   RN2118   VI(OFF)   RN2116   RN2117   RN2118   RN2116   RN2117   RN2118   RN2116   RN2116   RN2116   RN2117   RN2118   RN2116   RN2116   RN2117   RN2118   RN2118   RN2118   RN2118   RN2118   RN2118   RN2118   RN2118   RN2118   RN2116   RN2117   RN2118   RN2116   RN2116   RN2117   RN2118   RN2116   RN2116   RN2117   RN2118   RN2116   RN2116   RN2117   RN2116   RN2116   RN2116   RN2117   RN2118   RN2116   RN2116   RN2117   RN2118   RN2116   RN2117   RN2116   RN2117   RN2116   RN2117   RN2118   RN2116   RN2117   RN2116   RN2117   RN2116   RN2117   RN2118   RN2117   RN2118   RN2117   RN2118   RN2117   RN2118   RN2117   RN2118   RN2117   RN2118   RN2118   RN2117   RN2118			V <sub>CE(sat)</sub>	I <sub>C</sub> = -5 mA, I <sub>B</sub> = -0.25 mA	_	-0.1	-0.3	V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Input voltage (ON)	RN2114	V <sub>I(ON)</sub>	V <sub>CE</sub> = -0.2 V, I <sub>C</sub> = -5 mA	-0.5	_	-2.0	
RN2117   RN2118   N <sub>1</sub>   RN2118   N <sub>2</sub>   N <sub>2</sub>   N <sub>2</sub>   N <sub>2</sub>   N <sub>3</sub>   N <sub>3</sub>		RN2115			-0.6	_	-2.5	
RN2118   VI(OFF)   RN2114   VI(OFF)   RN2115   RN2116   RN2117   RN2118   RN2118   VI(OFF)   RN2114   RN2114   RN2114   RN2118   RN2114   RN2115   RN2116   RN2116   RN2116   RN2116   RN2118   RN2118   RN2116   RN2118   RN2116   RN211		RN2116			-0.7	_	-2.5	
Input voltage (OFF)   RN2114   RN2115   RN2116   RN2117   RN2118   RN2118   RN2114   RN2118   RN2118   RN2118   RN2118   RN2118   RN2114   RN2118   RN2114   RN2118   RN2114   RN2118   RN2118   RN2114   RN2118   RN2114   RN2118   RN2114   RN2118   RN2118   RN2114   RN2118   RN2116   RN2116   RN2117   RN2118   RN2116   RN2117   RN2118   RN2118   RN2116   RN2117   RN2118   RN2116   RN2116   RN2117   RN2118   RN2116   RN2117   RN2118   RN2116   RN2117   RN2116   RN2117   RN2116   RN2117   RN2118   RN2116   RN2117   RN2118   RN211		RN2117			-1.5	_	-3.5	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		RN2118			-2.5	_	-10.0	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Input voltage (OFF)	RN2114	V <sub>I(OFF)</sub>	$V_{CE} = -5 \text{ V}, I_{C} = -0.1 \text{ mA}$	-0.3	_	-0.9	V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		RN2115			-0.3	_	-1.0	
RN2118   RN2114		RN2116			-0.3	_	-1.1	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		RN2117			-0.3	_	-3.0	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		RN2118			-0.5	_	-5.7	
RN2118   MHz	Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = -10 V, I <sub>C</sub> = -5 mA	_	200	_	MHz
RN2115 RN2116 RN2117 RN2118 Resistor ratio  RN2114 RN2115 RN2115 RN2116 RN2117 RN2116 RN2117	Collector output capacitance		C <sub>ob</sub>		_	3.0	6.0	pF
RN2116 RN2117 RN2118 Resistor ratio  RN2114 RN2115 RN2116 RN2116 RN2117	Input resistance	RN2114	R <sub>1</sub>	-	0.7	1.0	1.3	kΩ
RN2117 RN2118 Resistor ratio  RN2114 RN2115 RN2116 RN2117		RN2115			1.54	2.2	2.86	
RN2118 Resistor ratio RN2114 RN2115 RN2116 RN2117 RN2117 RN2117 RN2118 R1/R2 - 0.1		RN2116			3.29	4.7	6.11	
Resistor ratio  RN2114 RN2115 RN2116 RN2117  RN2117  RN2117  RN2117  RN2117  RN2117  RN2117  RN2117  RN2117		RN2117			7.0	10.0	13.0	
RN2115 RN2116 RN2117 - 0.22		RN2118			32.9	47.0	61.1	
RN2116 — 0.47 — — — 2.13 —	Resistor ratio	RN2114	R1/R2	-	_	0.1	_	_
RN2117 — 2.13 —		RN2115			_	0.22	_	
		RN2116			_	0.47	_	
RN2118 - 4.7 -		RN2117			_	2.13	_	
		RN2118			_	4.7	_	

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### 9. Marking





Marking RN2116 Fig. 9.3

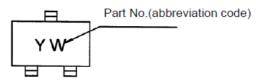


Fig. 9.5 Marking RN2118

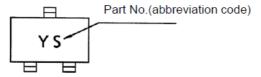


Fig. 9.2 Marking RN2115

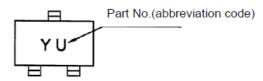
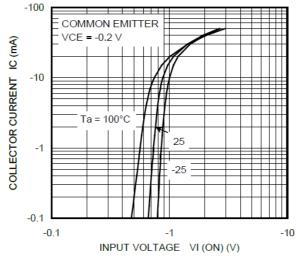


Fig. 9.4 Marking RN2117



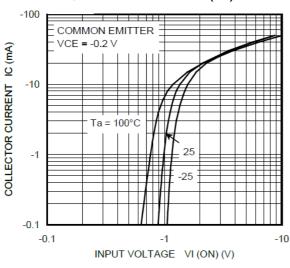
### 10. Characteristics Curves (Note)



-100

Fig. 10.1 RN2114 I<sub>C</sub>-V<sub>I(ON)</sub>

Fig. 10.2 RN2115 I<sub>C</sub>-V<sub>I(ON)</sub>



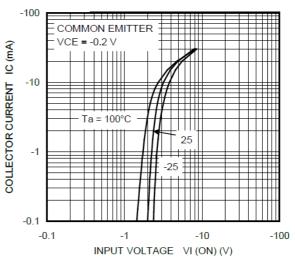


Fig. 10.3 RN2116 I<sub>C</sub>-V<sub>I(ON)</sub>

Fig. 10.4 RN2117 I<sub>C</sub>-V<sub>I(ON)</sub>

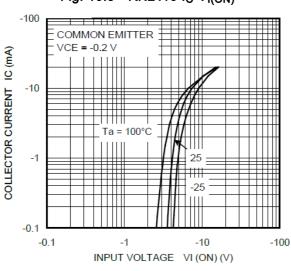


Fig. 10.5 RN2118  $I_{C}$ - $V_{I(ON)}$ 

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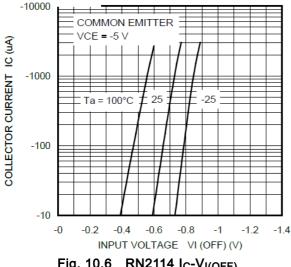


Fig. 10.6 RN2114 I<sub>C</sub>-V<sub>I(OFF)</sub>

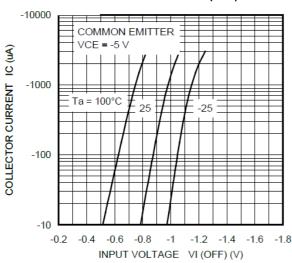


Fig. 10.8 RN2116 I<sub>C</sub>-V<sub>I(OFF)</sub>

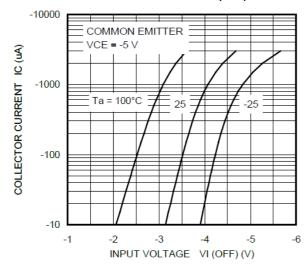


Fig. 10.10 RN2118 I<sub>C</sub>-V<sub>I(OFF)</sub>

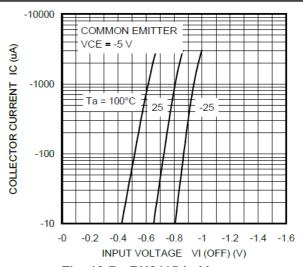


Fig. 10.7 RN2115 I<sub>C</sub>-V<sub>I(OFF)</sub>

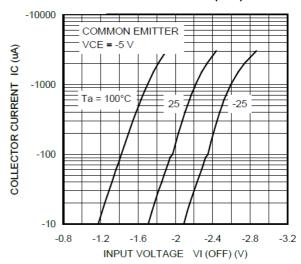
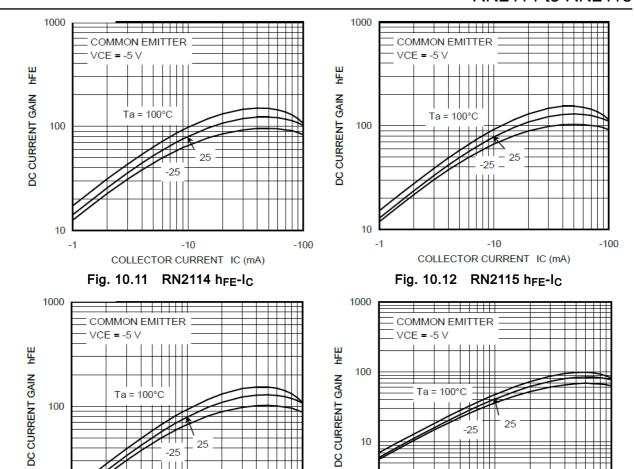


Fig. 10.9 RN2117 I<sub>C</sub>-V<sub>I(OFF)</sub>

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Fig. 10.13 RN2116 h<sub>FE</sub>-I<sub>C</sub>

-10

COLLECTOR CURRENT IC (mA)

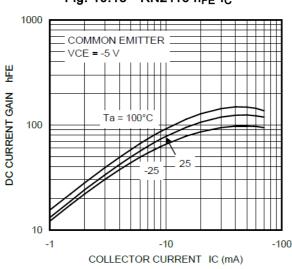


Fig. 10.14 RN2117 h<sub>FE</sub>-I<sub>C</sub>

-10

COLLECTOR CURRENT IC (mA)

Fig. 10.15 RN2118  $h_{FE}$ - $I_C$ 

-100



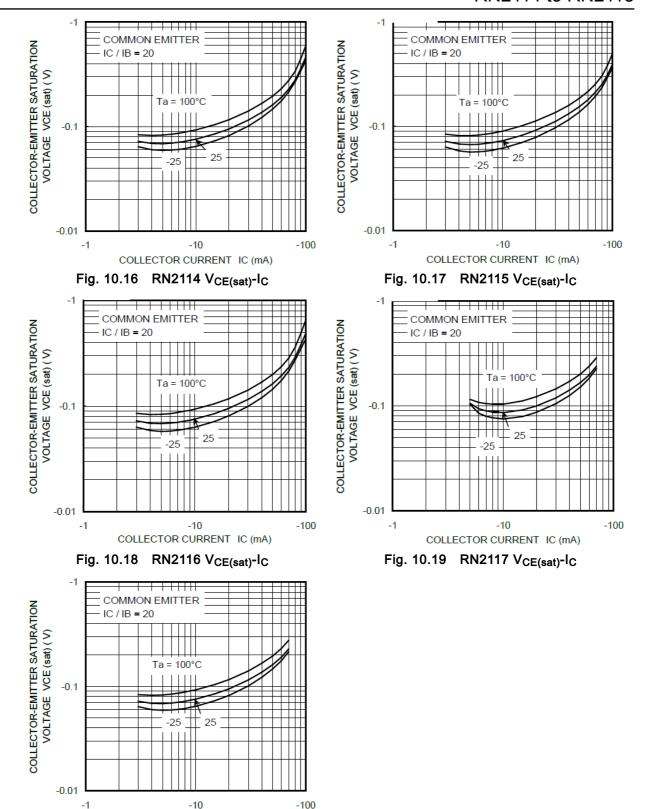


Fig. 10.20 RN2118 V<sub>CE(sat)</sub>-I<sub>C</sub>

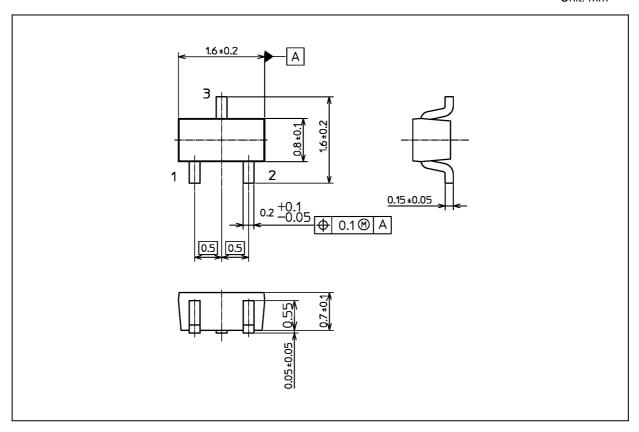
COLLECTOR CURRENT IC (mA)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



## **Package Dimensions**

Unit: mm



Weight: 2.4 mg (typ.)

Package Name(s)			
TOSHIBA: 2-2H1S			
Nickname: SSM			



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